

MODIFICATIONS

The power MOSFET is not directly compatible with the bipolar power transistor and cannot be used in a switched mode circuit without modification.

Irrespective of the power switching device used, be it a MOSFET or a bipolar power transistor, the associated pulse-width modulated switcher cannot normally be left on for more than 50 per cent of the total duty cycle. Under normal circumstances, a 50 per cent on time occurs only when the input voltage is very low and the output current is high. Conversely, the shortest on times occur when the input voltage is near to its peak and the output current is minimal.

Ideally, the pulse-width modulator should operate over a very wide duty cycle range to ensure close regulation with wide line and load extremes. Unfortunately, it has been impracticable to implement this approach in bipolar designs, since the gain of bipolar transistors decreases rapidly when operated in the short-pulse, high-current mode.

A power MOSFET's transconductance, on the other hand, does not vary so widely with current changes. This makes it much easier to drive a MOSFET directly, using a short duty cycle. Furthermore, the short conduction time at high input voltage leaves a relatively long time to reset the associated transformer and thus reduce the peak voltage across the MOSFET. Also the designer is able to use 500V rated devices in mains driven supplies in contrast to the usual 800V rating often needed for circuits featuring bipolar devices.

PROTECTION

Some protection is of course necessary. The MOSFET shown in Fig. 1, for example, features clamping diodes (Zener diodes 1 and 2) to limit the circuit's maximum gate voltage to 18V. Zener 3 which comprises four series-connected 120V diodes, restricts the source/drain swing to 450V to give a safe working margin.

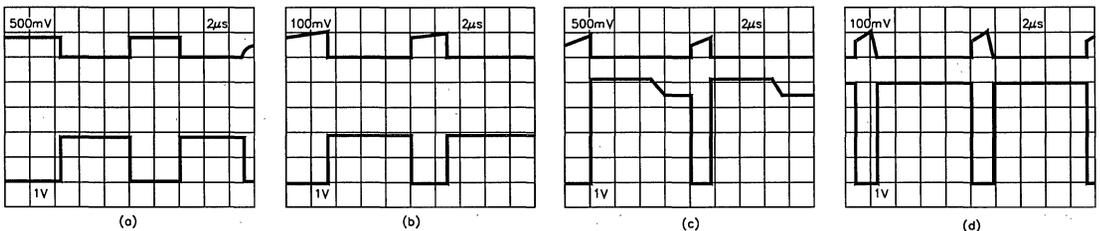


Figure 2. Switching Waveforms. With an 85V Line and a 20A Load (a) Shows Drawn Current on the Upper Trace and Drain Voltage on the Lower. The Load is Cut to 5A in (b), While (c) and (d) Show the Same Parameters at a 265V Line Voltage with Respective Loads of 20A and 5A.

The resistor/capacitor/diode snubber formed by $R_1/C_2/D_3$ conforms in the principle to the approach outlined in the earlier article, except that it is allowed to float. For more details on this and other related topics, refer to International Rectifier's application note AN-939.

Trials have shown that worst-case efficiency occurs at virtually maximum input voltage with minimum loading. Here efficiency drops to just under 70 percent, compared with 76 percent at maximum output. Dissipation is thus around 8W at maximum output and slightly higher than this value when the supply is lightly loaded.

OPERATION

The off-screen photographs show how the circuit functions. Fig. 2 demonstrates how the pulse-width modulator controls the MOSFET's conduction time with respect to various load and line conditions. At one extreme, the input voltage is down to 85V, while output is at 20A. Fig. 2a shows the MOSFET on for 4µs when operating at a duty cycle of approximately 44 percent. When operating at the other extreme, ie 265V input and 5A output, the MOSFET is on for approximately 1µs, which corresponds to a 10 percent duty cycle. Note how the gate/source waveforms which are depicted in Fig. 3 relate to the operating levels shown in Fig. 2.

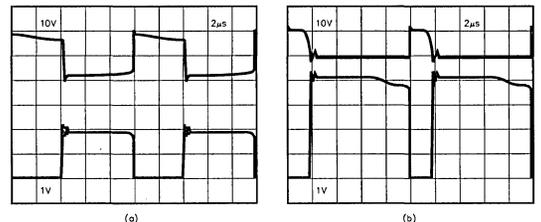
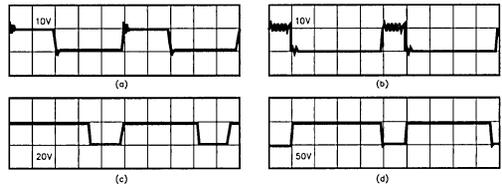


Figure 3. Gate/Source Waveforms. These Were Recorded with the Unit Under Full Load, (a) with a Line Voltage of 85V and (b) with a Line Voltage of 265V. The Upper Traces Show Gate/Source Voltage While the Lower Show Drain Voltage.

APPLICATION NOTES – SG1526

Typical voltage waveforms across the output rectifiers are shown in Fig. 4. Note that while the forward rectifier D1 blocks a peak voltage (including the commutation transient) of about 12V, D2 has to withstand around 75V for a 5V output, due to the short conduction cycle. Both of these diodes contribute to the system's net losses. Indeed, these devices dissipate some 30 to 50 percent of the switching energy, and represent a major problem in designing low output voltage power supplies. Losses from the rectifier diodes are approximately the same for both the 5 and 15V supply designs.



TRACE	PARAMETER	CONDITIONS	VERTICAL	HORIZONTAL
a	D1 VOLTAGE	35V LINE	10V/DIV	
b	D2 VOLTAGE	5A LOAD	20V/DIV	2μ SEC/DIV
c	D1 VOLTAGE	265V LINE	20V/DIV	
d	D2 VOLTAGE	5A LOAD	50V/DIV	

Figure 4. Output Circuit Waveforms. The Upper Traces Show the Voltage Waveform Appearing Across D1, While the Lower Covers Rectifier D2. In Both Cases, Load is at 5A; (a) with the Input Voltage at 85V and (b) at 265V.

